

Vishay General Semiconductor

# **High-Voltage Schottky Rectifier**

High Barrier Technology for Improved High Temperature Performance



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub> 3.0 A				
$V_{RRM}$	90 V, 100 V			
I <sub>FSM</sub>	100 A			
V <sub>F</sub>	0.65 V			
I <sub>R</sub>	20 μΑ			
T <sub>.I</sub> max.	175 °C			

#### **FEATURES**

- · Guardring for overvoltage protection
- · Low power losses and high efficiency
- · Low forward voltage drop
- · Low leakage current
- High forward surge capability
- High frequency operation
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

#### TYPICAL APPLICATIONS

For use in middle voltage high frequency inverters, freewheeling, dc-to-dc converters, and polarity protection applications.

#### **MECHANICAL DATA**

Case: DO-201AD

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2

whisker test

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	SB3H90	SB3H100	UNIT	
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	90	100	V	
Maximum working reverse voltage	$V_{RWM}$	90	100	٧	
Maximum DC blocking voltage	V <sub>DC</sub>	90	100	V	
Maximum average forward rectified current at T <sub>L</sub> = 90 °C	I <sub>F(AV)</sub>	3.0		Α	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	100		А	
Peak repetitive reverse surge current at $t_p = 2.0 \mu s$ , 1 kHz	I <sub>RRM</sub>	1.0		Α	
Critical rate of rise of reverse voltage	dV/dt	10 000		V/μs	
Storage temperature range	T <sub>STG</sub>	- 55 to + 175		°C	
Maximum operating junction temperature	T <sub>J</sub>	175			

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CO	ONDITIONS	SYMBOL	SB3H90 SB3H100		UNIT
Maximum instantaneous forward voltage <sup>(1)</sup>	I <sub>F</sub> = 3.0 A I <sub>F</sub> = 3.0 A	T <sub>J</sub> = 25 °C T <sub>J</sub> = 125 °C	$V_{F}$	0.i 0.i		V
Maximum reverse current at rated V <sub>R</sub> <sup>(2)</sup>		$T_J = 25 ^{\circ}\text{C}$ $T_J = 125 ^{\circ}\text{C}$	I <sub>R</sub>	20 4.0		μA mA

#### Notes:

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

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<b>THERMAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	SB3H90	SB3H100	UNIT
Maximum thermal resistance (1)	$R_{ hetaJA} \ R_{ hetaJL}$	50 20		°C/W

#### Note:

(1) P.C.B. mounted with 0.2 x 0.2" (5.0 x 5.0 mm) copper pad areas

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
SB3H100-E3/54	1.09	54	1400	13" diameter paper tape and reel	
SB3H100-E3/73	1.09	73	1000	Ammo pack packaging	
SB3H100HE3/54 <sup>(1)</sup>	1.09	54	1400	13" diameter paper tape and reel	
SB3H100HE3/73 (1)	1.09	73	1000	Ammo pack packaging	

#### Note:

(1) Automotive grade AEC Q101 qualified

#### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

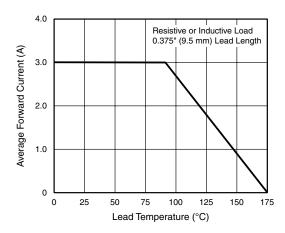


Figure 1. Forward Current Derating Curve

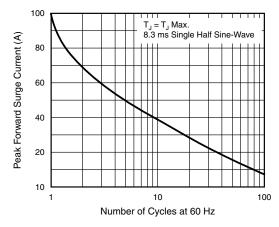


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current

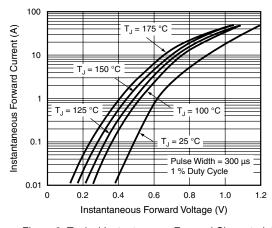


Figure 3. Typical Instantaneous Forward Characteristics

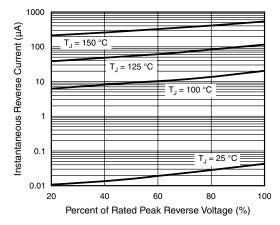


Figure 4. Typical Reverse Characteristics



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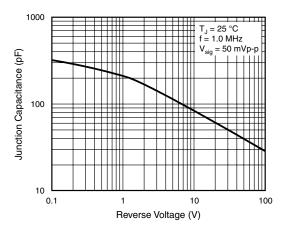


Figure 5. Typical Junction Capacitance

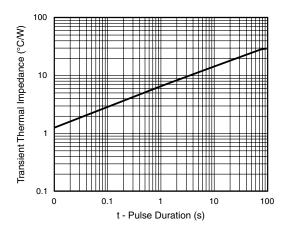
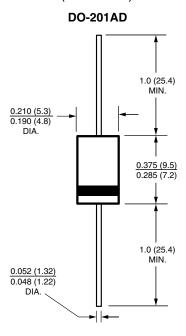


Figure 6. Typical Transient Thermal Impedance

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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